

Standard Recovery Diodes (Stud Version), 70 A



DO-203AB (DO-5)

FEATURES

- High surge current capability
- Designed for a wide range of applications
- Stud cathode and stud anode version
- Leaded version available
- Types up to 1600 V V_{RRM}

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- Battery charges

PRODUCT SUMMARY

$I_{F(AV)}$	70 A
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MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	TEST CONDITIONS	70HF(R)		UNITS
		10 TO 120	140/160	
I _{F(AV)}		70	70	A
	T _C	140	110	°C
I _{F(RMS)}		110		A
I _{FSM}	50 Hz	1200		A
	60 Hz	1250		
I ² t	50 Hz	7100		A ² s
	60 Hz	6450		
V _{RRM}	Range	100 to 1200	1400/1600	V
T _J		- 65 to 180	- 65 to 150	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

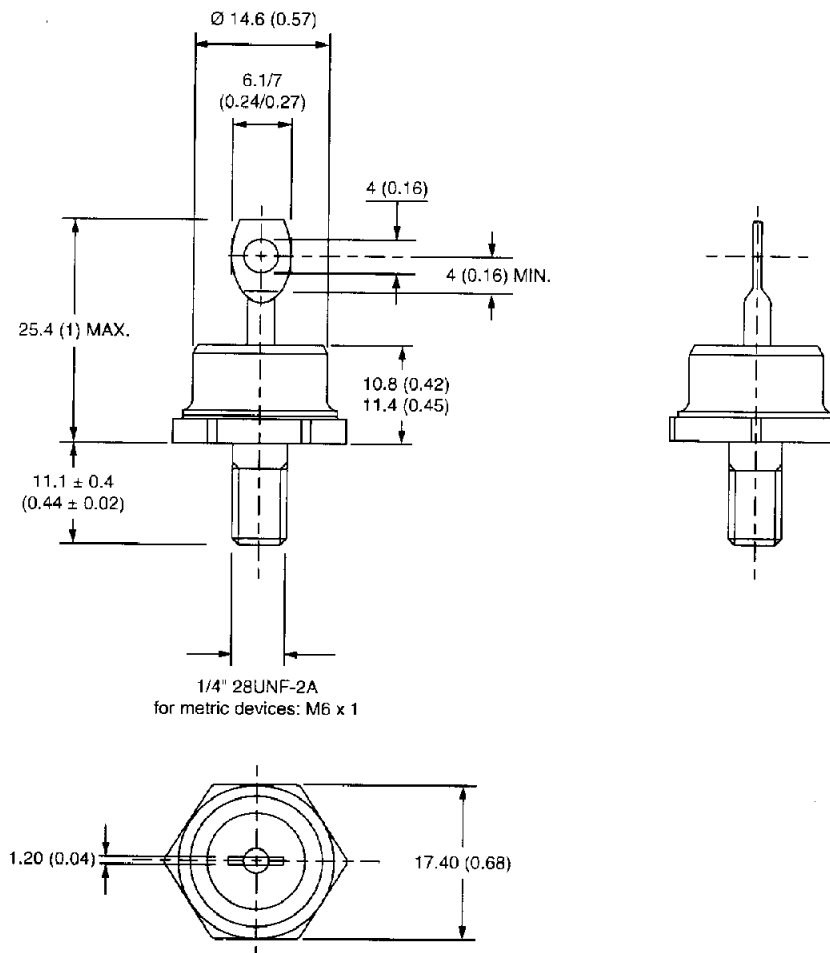
TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$V_{R(BR)}$, MINIMUM AVALANCHE VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA
70HF(R)	10	100	200	200	15
	20	200	300	300	
	40	400	500	500	
	60	600	720	725	9
	80	800	960	950	
	100	1000	1200	1150	
	120	1200	1440	1350	
	140	1400	1650	1550	4.5
	160	1600	1900	1750	

FORWARD CONDUCTION								
PARAMETER	SYMBOL	TEST CONDITIONS			70HF(R)		UNITS	
					10 TO 120	140/160		
Maximum average forward current at case temperature	I _{F(AV)}	180° conduction, half sine wave			70		A	
					140	110	°C	
Maximum RMS forward current	I _{F(RMS)}				110		A	
Maximum peak, one cycle forward, non-repetitive surge current	I _{FSM}	t = 10 ms	No voltage reapplied	Sinusoidal half wave, initial T _J = T _J maximum	1200		A	
		t = 8.3 ms			1250			
		t = 10 ms	100 % V _{RRM} reapplied		1000			
		t = 8.3 ms			1050			
Maximum I ² t for fusing	I ² t	t = 10 ms	No voltage reapplied		7100		A ² s	
		t = 8.3 ms			6450			
		t = 10 ms	100 % V _{RRM} reapplied		5000			
		t = 8.3 ms			4550			
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied			71 000		A ² √s	
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % × π × I _{F(AV)}) < I < π × I _{F(AV)} , T _J = T _J maximum			0.79		V	
High level value of threshold voltage	V _{F(TO)2}	(I > π × I _{F(AV)}), T _J = T _J maximum			1.00			
Low level value of forward slope resistance	r _{f1}	(16.7 % × π × I _{F(AV)}) < I < π × I _{F(AV)} , T _J = T _J maximum			2.33		mΩ	
High level value of forward slope resistance	r _{f2}	(I > π × I _{F(AV)}), T _J = T _J maximum			1.53			
Maximum forward voltage drop	V _{FM}	I _{pk} = 220 A, T _J = 25 °C, t _p = 400 μs rectangular wave			1.35	1.46	V	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	70HF(R)		UNITS
			10 TO 120	140/160	
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65 to 180	- 65 to 150	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.45		K/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25		
Maximum allowable mounting torque (+ 0 %, - 10 %)		Not lubricated thread, tightening on nut ⁽¹⁾	3.4 (30)		N · m (lbf · in)
		Lubricated thread, tightening on nut ⁽¹⁾	2.3 (20)		
		Not lubricated thread, tightening on hexagon ⁽²⁾	4.2 (37)		
		Lubricated thread, tightening on hexagon ⁽²⁾	3.2 (28)		
Approximate weight			17		g
			0.6		oz.
Case style		See dimensions - link at the end of datasheet	DO-203AB (DO-5)		

DO-203AB (DO-5) for 70HF(R) and 71HF(R) Series

DIMENSIONS FOR 70HF(R) SERIES in millimeters (inches)



DO-203AB (DO-5) for
70HF(R) and 71HF(R) Series

DIMENSIONS FOR 71HF(R) SERIES in millimeters (inches)

